

## **General Description**

The WSF3036A is the highest performance trench N-ch MOSFETs with extreme high cell density , which provide excellent  $R_{\text{DSON}}$  and gate charge for most of the synchronous buck converter applications .

The WSF3036A meet the RoHS and Green Product requirement, 100% EAS guaranteed with full function reliability approved.

#### **Features**

- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent CdV/dt effect decline
- 100% EAS Guaranteed
- Green Device Available

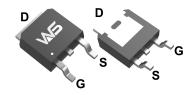
## **Product Summery**

BVDSS	RDSON	ID
30V	19mΩ	32A

## **Applications**

- High Frequency Point-of-Load Synchronous Buck Converter for MB/NB/UMPC/VGA
- Networking DC-DC Power System
- Load Switch

## **TO-252 Pin Configuration**





# **Absolute Maximum Ratings**

Symbol	Parameter	Rating	Units
$V_{DS}$	Drain-Source Voltage	30	V
$V_{GS}$	Gate-Source Voltage	±20	V
I <sub>D</sub> @T <sub>C</sub> =25℃	Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>1</sup>	32	Α
I <sub>D</sub> @T <sub>C</sub> =100℃	Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>1</sup> 22		
I <sub>DM</sub>	Pulsed Drain Current <sup>2</sup> 50		А
EAS	Single Pulse Avalanche Energy <sup>3</sup>	60	mJ
I <sub>AS</sub>	Avalanche Current	18	Α
P <sub>D</sub> @T <sub>C</sub> =25℃	Total Power Dissipation <sup>4</sup> 18		W
T <sub>STG</sub>	Storage Temperature Range -55 to 150		$^{\circ}$
$T_J$	Operating Junction Temperature Range	-55 to 150	$^{\circ}$

## **Thermal Data**

Symbol	Parameter	Тур.	Max.	Unit
$R_{\theta JA}$	Thermal Resistance Junction-Ambient (<10s) <sup>1</sup>		25	°C/W
$R_{ heta JA}$	Thermal Resistance Junction-ambient (Steady State) <sup>1</sup>	62		°C/W
R <sub>eJC</sub>	Thermal Resistance Junction-Case <sup>1</sup>		5	°C/W



## Electrical Characteristics (T<sub>J</sub>=25 °C, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V , I <sub>D</sub> =250uA	30			V
$\triangle BV_{DSS}/\triangle T_{J}$	BVDSS Temperature Coefficient	Reference to 25℃ , I <sub>D</sub> =1mA		0.023		V/°C
В	Static Drain-Source On-Resistance <sup>2</sup>	V <sub>GS</sub> =10V , I <sub>D</sub> =10A		19	30	m()
R <sub>DS(ON)</sub>		V <sub>GS</sub> =4.5V , I <sub>D</sub> =5A		30	42	mΩ
V <sub>GS(th)</sub>	Gate Threshold Voltage	)/ -\/   -250A	1.0	1.5	2.5	V
$\triangle V_{GS(th)}$	V <sub>GS(th)</sub> Temperature Coefficient	$V_{GS}=V_{DS}$ , $I_D=250uA$		-5.2		mV/℃
	Dunin Course Lookers Current	V <sub>DS</sub> =24V , V <sub>GS</sub> =0V , T <sub>J</sub> =25℃			1	· uA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =24V , V <sub>GS</sub> =0V , T <sub>J</sub> =55℃			5	
I <sub>GSS</sub>	Gate-Source Leakage Current	$V_{GS}$ = $\pm 20V$ , $V_{DS}$ = $0V$			±100	nA
gfs	Forward Transconductance	V <sub>DS</sub> =15V , I <sub>D</sub> =10A		9.5		S
Rg	Gate Resistance	V <sub>DS</sub> =24V , V <sub>GS</sub> =0V , f=1MHz		2.4		Ω
$Q_g$	Total Gate Charge (4.5V)	V <sub>DS=</sub> 20V , V <sub>GS</sub> =4.5V , I <sub>D</sub> =10A		6.9		
$Q_gs$	Gate-Source Charge			1.2		nC
Q <sub>gd</sub>	Gate-Drain Charge			2.35		
T <sub>d(on)</sub>	Turn-On Delay Time	$V_{DD}$ =12V , $V_{GS}$ =10V , $R_{G}$ =3.3 $\Omega$ , $I_{D}$ =5A		3.89		
T <sub>r</sub>	Rise Time			9.1		200
T <sub>d(off)</sub>	Turn-Off Delay Time			20		ns
T <sub>f</sub>	Fall Time			5.5		1
Ciss	Input Capacitance	V <sub>DS</sub> =25V , V <sub>GS</sub> =0V , f=1MHz		510		
C <sub>oss</sub>	Output Capacitance			62		pF
C <sub>rss</sub>	Reverse Transfer Capacitance			44		

## **Guaranteed Avalanche Characteristics**

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
EAS	Single Pulse Avalanche Energy <sup>5</sup>	V <sub>DD</sub> =25V , L=0.1mH , I <sub>AS</sub> =10A	15			mJ

#### **Diode Characteristics**

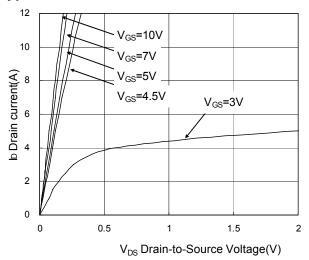
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
Is	Continuous Source Current <sup>1,6</sup>	V <sub>G</sub> =V <sub>D</sub> =0V , Force Current			8.5	Α
I <sub>SM</sub>	Pulsed Source Current <sup>2,6</sup>				35	Α
$V_{SD}$	Diode Forward Voltage <sup>2</sup>	V <sub>GS</sub> =0V , I <sub>S</sub> =15A , T <sub>j</sub> =25℃			1.2	V

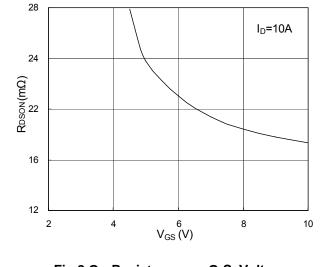
#### Note:

- 1.The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2OZ copper,t<10sec.
- 2. The data tested by pulsed , pulse width  $\leq$  300us , duty cycle  $\leq$  2%
- 3.The EAS data shows Max. rating . The test condition is  $V_{\text{DD}}$ =25V, $V_{\text{GS}}$ =10V,L=0.1mH, $I_{\text{AS}}$ =10A
- 4. The power dissipation is limited by 150 °C junction temperature
- 5. The Min. value is 100% EAS tested guarantee.
- 6. The data is theoretically the same as  $I_D$  and  $I_{DM}$ , in real applications, should be limited by total power dissipation.



## **Typical Characteristics**





**Fig.1 Typical Output Characteristics** 

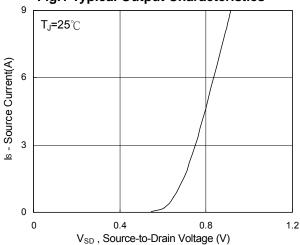


Fig.2 On-Resistance vs. G-S Voltage

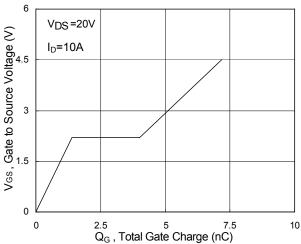


Fig.3 Forward characteristics of reverse

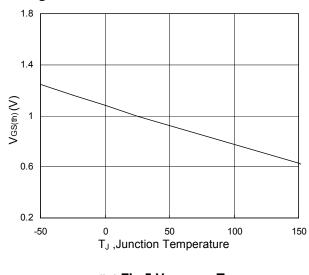
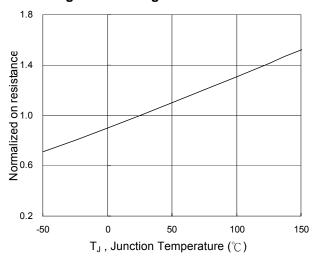


Fig.4 Gate-charge characteristics



(°C) Fig.5  $V_{GS(th)}$  vs.  $T_J$  Fig.6 Normalized  $R_{DSON}$  vs.  $T_J$ 



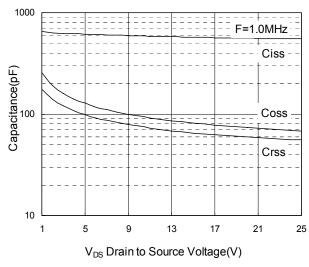


Fig.7 Capacitance

Fig.8 Safe operating area

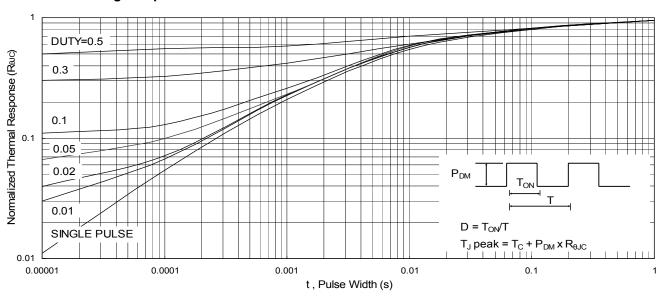
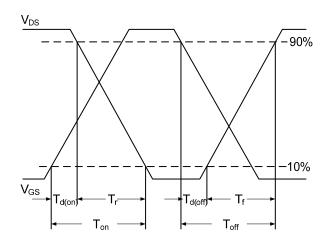


Fig.9 Normalized Maximum Transient Thermal Impedance



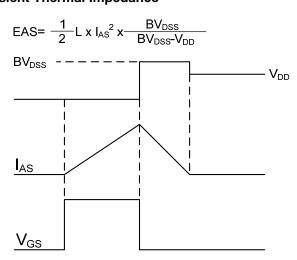


Fig.10 Switching time waveform

Fig.11 Unclamped inductive switching wave.



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